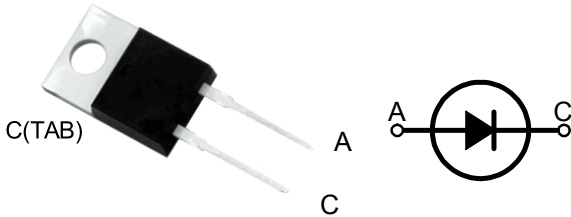


# SD1001 thru 1016

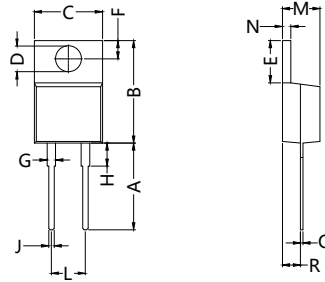
## Discrete Diodes



A=Anode, C=Cathode, TAB=Cathode

	$V_{RSM}$ V	$V_{RRM}$ V
<b>SD1001</b>	200	100
<b>SD1002</b>	300	200
<b>SD1004</b>	500	400
<b>SD1006</b>	700	600
<b>SD1008</b>	900	800
<b>SD1010</b>	1100	1000
<b>SD1012</b>	1300	1200
<b>SD1016</b>	1700	1600

### Dimensions TO-220AC



Dim.	Millimeter	
	Min.	Max.
A	12.70	13.97
B	14.73	16.00
C	9.91	10.66
∅D	3.54	4.08
E	5.85	6.85
F	2.54	3.18
G	1.15	1.65
H	2.79	5.84
J	0.64	1.01
L	5.08BSC	
M	4.32	4.82
N	1.14	1.39
Q	0.35	0.56
R	2.29	2.79

Symbol	Test Conditions	Maximum Ratings	Unit
$I_{F(AV)M}$	$T_C=95^\circ\text{C}; 180^\circ$ sine	10	A
$I_{FSM}$	$T_{VJ}=45^\circ\text{C};$ $V_R=0\text{V};$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	150 175	A
	$T_{VJ}=150^\circ\text{C};$ $V_R=0\text{V};$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	125 170	
$I^2t$	$T_{VJ}=45^\circ\text{C};$ $V_R=0\text{V};$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	230 260	$\text{A}^2\text{s}$
	$T_{VJ}=150^\circ\text{C};$ $V_R=0\text{V};$ $t=10\text{ms}$ (50Hz), sine $t=8.3\text{ms}$ (60Hz), sine	200 220	
$T_{VJ}$ $T_{VJM}$ $T_{stg}$		-40...+150 150 -40...+150	$^\circ\text{C}$
$M_d$	Mounting torque	0.4...0.6	Nm
Weight		2	g

Symbol	Test Conditions	Characteristic Values	Unit
$I_R$	$T_{VJ}=T_{VJM}; V_R=V_{RRM}$	$\leq 1$	mA
$V_F$	$I_F=10\text{A}; T_{VJ}=25^\circ\text{C}$	$\leq 1.25$	V
$V_{TO}$	For power-loss calculations only	0.85	V
$r_T$	$T_{VJ}=T_{VJM}$	16	$\text{m}\Omega$
$R_{thJC}$	DC current	1.29	K/W

**Sirectifier®**

# SD1001 thru 1016

## Discrete Diodes

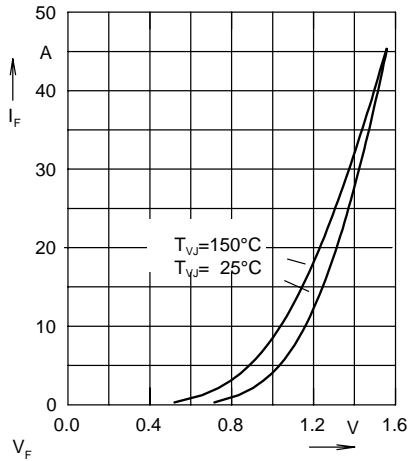


Fig. 1 Forward current versus voltage drop per diode

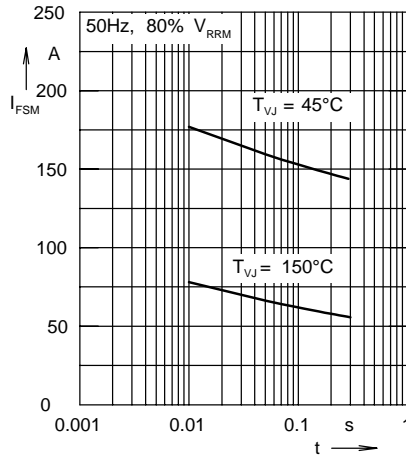


Fig. 2 Surge overload current

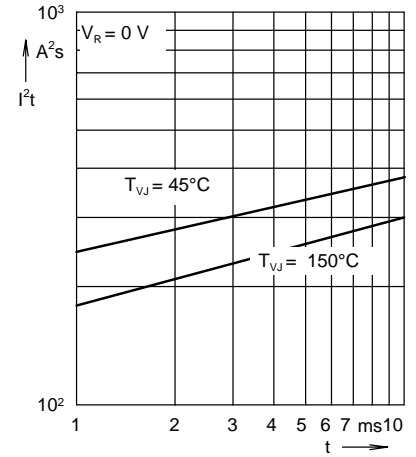


Fig. 3  $I^2t$  versus time per diode

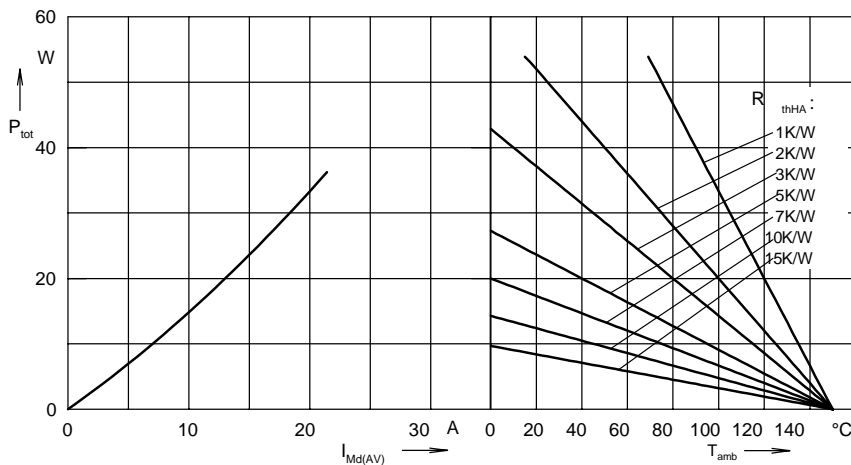


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 18 0 °

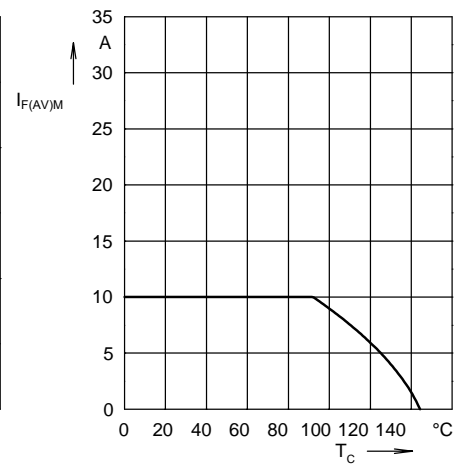


Fig. 5 Max. forward current versus case temperature

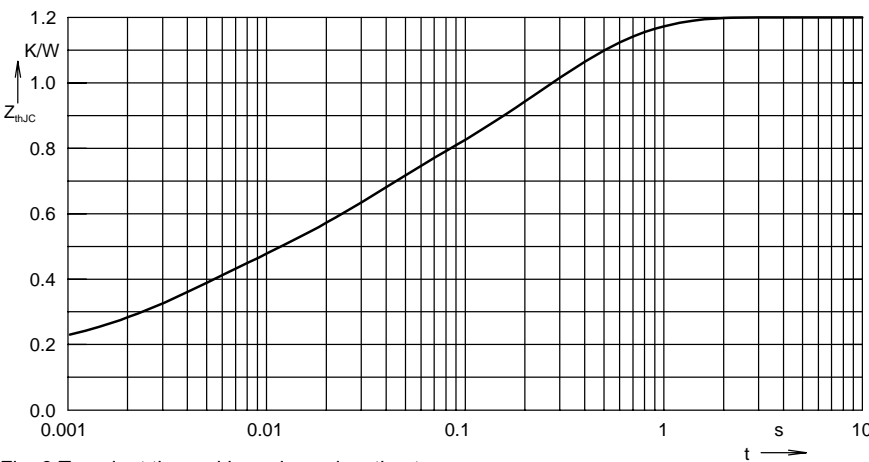


Fig. 6 Transient thermal impedance junction to case



Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.01362	0.0001
2	0.1962	0.00316
3	0.267	0.023
4	0.3052	0.4
5	0.218	0.15